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30A, 100V - 200V Trench Schottky Rectifiers

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

I^2PAK







Version: D15

TYPICAL APPLICATIONS

Trench Schottky barrier rectifier is designed for high frequency switched mode power supplies such as adapters, lighting, and DC/DC converters.

MECHANICAL DATA

Case: I²PAK

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" menas green compound (halogen-free) Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

Polarity: As marked

Weight: 1.6 g (approximately)

MAXIMUM RATINGS	S AND EL	ECTRICAL	CHARAC	TERIS	TICS ($I_A = 25$	o°C unle	ess othe	erwise r	noted)		
PARAMETER		SYMBOL		30H CW		30H CW		30H CW		30H CW	UNIT	
Maximum repetitive peak reverse voltage			V_{RRM}	100 120 150 200			00	V				
Maximum average	per device		1	30							^	
forward rectified current	ре	r diode	I _{F(AV)}	15							Α	
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	200					А				
Voltage rate of change (Rated V _R)			dV/dt	10000					V/µs			
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
Instantaneous forward voltage per diode (Note1)	I _F = 15A	T _J = 25°C	V _F	0.69	0.78	0.75	0.84	0.81	0.90	0.84	0.92	- v
		T _J = 125°C		0.61	0.68	0.64	0.73	0.68	0.77	0.70	0.79	
		T _J = 25°C	I _R	-	250	-	250	-	150	-	150	μΑ
		T _J = 125°C		10	35	10	35	3	20	3	20	mA
Typical thermal resistance per diode			$R_{ heta JC}$	2.7						°C/W		
Operating junction temperature range			T_J	- 55 to +150						°C		
Storage temperature range			T _{STG}	- 55 to +150						°C		

Note 1: Pulse test with pulse width = $300\mu s$, 1% duty cycle

Document Number: DS_D1411045



ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
TSI30HXXXCW (Note 1, 2)	C0	G	I ² PAK	50 / Tube		

Note 1: "XXX" defines voltage from 100V (TSI30H100CW) to 200V (TSI30H200CW)

Note 2: Whole series with green compound

EXAMPLE							
PREFERRED PART NO. PART NO.		PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION			
TSI30H120CW C0G	TSI30H120CW	C0	G	Green compound			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

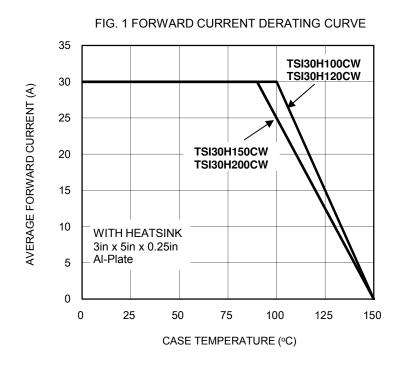
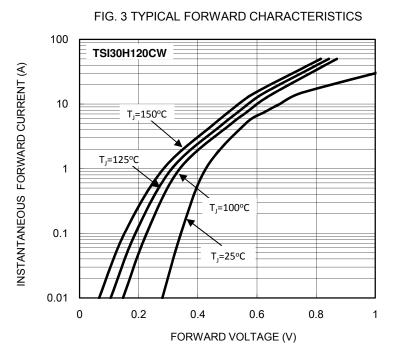


FIG. 2 TYPICAL FORWARD CHARACTERISTICS 100 TSI30H100CW INSTANTANEOUS FORWARD CURRENT (A) 10 T₁=150°C T₁=125°C T_J=100°C 0.1 T_J=25°C 0.01 0 0.2 0.6 8.0 0.4 FORWARD VOLTAGE (V)



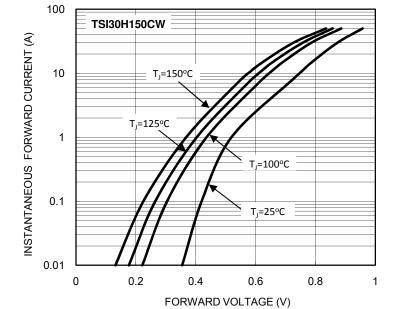


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

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FIG. 5 TYPICAL FORWARD CHARACTERISTICS

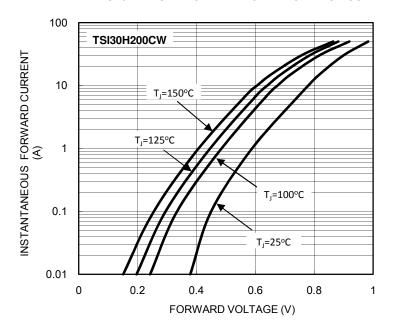


FIG. 6 TYPICAL REVERSE CHARACTERISTICS

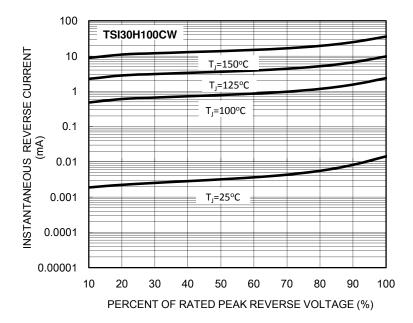


FIG. 7 TYPICAL REVERSE CHARACTERISTICS

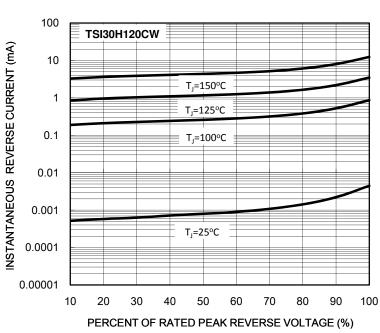


FIG. 8 TYPICAL REVERSE CHARACTERISTICS

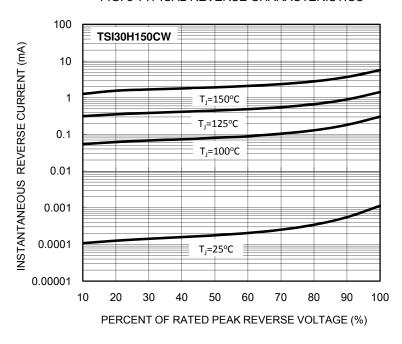


FIG. 9 TYPICAL REVERSE CHARACTERISTICS

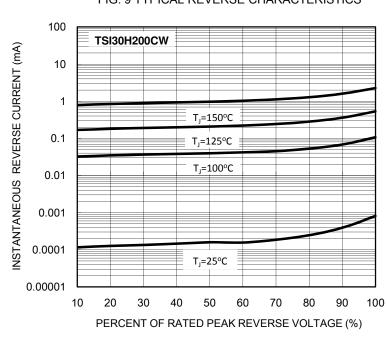
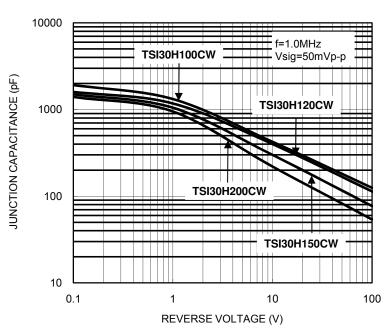


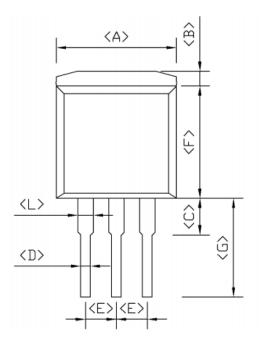
FIG. 10 TYPICAL JUNCTION CAPACTIANCE

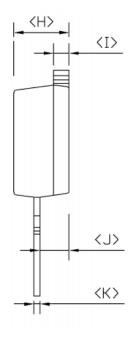




PACKAGE OUTLINE DIMENSIONS

I²PAK





DIM.	Unit	(mm)	Unit (inch)			
DIIVI.	Min	Max	Min	Max		
Α	1	10.50	-	0.413		
В	1.14	1.40	0.045	0.055		
С	2.80	4.20	0.110	0.165		
D	0.68	0.94	0.027	0.037		
Е	2.41	2.67	0.095	0.105		
F	9.07	9.47	0.357	0.373		
G	7.79	9.35	0.307	0.368		
Н	4.40	4.70	0.173	0.185		
I	1.14	1.40	0.045	0.055		
J	2.20	2.80	0.087	0.110		
K	0.35	0.64	0.014	0.025		
Ĺ	0.95	1.45	0.037	0.057		

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code

F = Factory Code



Taiwan Semiconductor

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